## 

# High-Speed, CMOS, Quad, SPST Analog Switch

#### **General Description**

Maxim's HI-201HS is a monolithic, CMOS, quad, singlepole-single-throw (SPST), high-speed analog switch featuring fast switching times (toFF, toN ≤ 50ns) and low on resistance ( $50\Omega$  max). It is pin compatible with the industry-standard DG201A.

Maxim's new high-voltage silicon-gate technology increases the maximum supply-voltage rating to 44V. This improvement allows continuous operation with ±20V supplies, which is not permitted with the original manufacturer's devices. Maxim's HI-201HS operates from dual supplies ranging from ±5V to ±20V, or from single supplies from +12V to +20V. Logic levels are TTL-/CMOS-compatible with single or dual supplies within these ranges.

Maxim's HI-201HS is guaranteed not to latch up if power supplies are disconnected while the analog-switch inputs are present, provided the switch continuous-current ratings are not exceeded. When powered up, the HI-201HS will switch analog signals up to the power-supply rails.

#### **Applications**

Automatic Test Equipment (ATE) Heads-Up Displays Communication Systems Sample-and-Hold Circuits Military Integrator Reset Circuits

#### **Features**

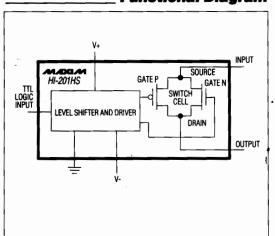
- ♦ Guaranteed Single-Supply Operation: +12V to +20V
- ♦ Guaranteed Dual Supplies: ±5V to ±20V
- ◆ Fast Switching Times: ton = 30ns toff = 40ns
- ♦ Low, 50Ω Max On Resistance
- **♦ TTL-/CMOS-Compatible**
- **♦ 44V Max Supply Rating**

#### Ordering Information

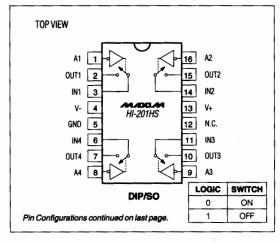
PART	TEMP. RANGE	PIN-PACKAGE
HI3-0201HS-5	0°C to +70°C	16 Plastic DIP
HI6-0201HS-5	0°C to +70°C	16 Narrow SO
HI1-0201HS-5	0°C to +70°C	16 CERDIP
HI0-0201HS-6	0°C to +70°C	Dice*
HI3-0201HS-9	-40°C to +85°C	16 Plastic DIP
HI6-0201HS-9	-40°C to +85°C	16 Narrow SO
HI1-0201HS-9	-40°C to +85°C	16 CERDIP
HI1-0201HS-2	-55°C to +125°C	16 CERDIP
HI4-0201HS-8	-55°C to +125°C	20 LCC**

- \* Contact factory for dice specifications.
- \*\* Contact factory for availability.

#### Functional Diagram



#### Pin Configurations



#### **ABSOLUTE MAXIMUM RATINGS**

Voltage Referenced to V-	Continuous Pow
V+ 44V	16-Pin DIP (de
GND 25V	16-Pin Wide St
Digital inputs V <sub>S</sub> , V <sub>D</sub> (Note 1) (V 4V) to (V+ + 4V) or 30mA	16-Pin CERDIF
(whichever occurs first)	20-Pin LCC (de
Current (any terminal, except S or D) 30mA	Operating Temp
Continuous Current, S or D	HI-0201HS-5/-
Peak Current, S or D	HI-0201HS-9
(pulsed at 1ms, 10% duty cycle max) 40mA	HI-0201HS-2/-
	Storage Temper

Note 1: Signals on Sx, Dx, or INx exceeding V+ or V- are clamped by internal diodes. Limit forward current to maximum current ratings.

Note 2: All leads soldered or welded to PC board.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

#### **ELECTRICAL CHARACTERISTICS**

(V+ = 15V, V- = -15V, GND = 0V,  $T_A$  = +25°C, unless otherwise noted.)

		CONDITIONS		HI-201HS-2/-8			HI-201HS-5/-6/-9					
PARAMETER	SYMBOL			MIN (Note 3)	TYP (Note 4)	MAX	MIN (Note 3)	TYP (Note 4)	MAX	UNITS		
SWITCH												
Analog-Signal Range	VANALOG			-15		15	-15		15	٧		
Drain-Source On Resistance (Note 5)	rDS (on)	V <sub>D</sub> = ±10V,	V <sub>IN</sub> = 0.8V, is = 1mA		30	50		30	50	Ω		
Source-Off Leakage	IS (off)	V 2.0V	Vs = 14V, VD = -14V	-1	±0.01	1	-1	±0.01	1			
Current		$V_{IN} = 3.0V$	Vs = -14V, VD = 14V	-1	±0.02	1	-1	±0.02	1	nA		
Drain-Off Leakage	ID (off)			\/ 2 O\/	VD = 14V, VS = -14V	-1	±0.01	1	-1	±0.01	1	- ^
Current		VIN = 3.0V	V <sub>D</sub> = -14V, V <sub>S</sub> = 14V	-1	±0.02	1	-1	±0.02	1	nA		
Drain-On Leakage	ID (on)	V <sub>D</sub> = -14V, V	VIN = 0.8V	-1	±0.10	1	-1	±0.10	1			
Current (Note 6)		V <sub>D</sub> = 14V, V	'IN = 0.8V	-1	±0.15	1	-1	±0.15	1	nΑ		
LOGIC INPUT												
Input Current with	INH	VIN = 3.0V		-1	0	1	-1	0	1			
Input Voltage High		VIN = 15V		-1	0	1	-1	0	1	μΑ		
Input Current with Input Voltage Low	INL	V <sub>IN</sub> = 0.8V		-1	0	1	-1	0	1	μА		

### **ELECTRICAL CHARACTERISTICS (continued)**

(V+ = 15V, V- = -15V, GND = 0V,  $T_A$  = +25°C, unless otherwise noted.)

		************		HI-2	201HS-2	-8	HI-201HS-5/-6/-9			
PARAMETER	SYMBOL			MIN (Note 3)	TYP (Note 4)	MAX	MIN (Note 3)	TYP (Note 4)	MAX	UNITS
DYNAMIC				•			•			•
Turn-On Time	ton	Figure 6			30	50		30	50	ns
Turn-Off Time	toff	Ciouro 6			40	50		<b>1</b> 40	50	
Turn-Off Time	toff2	Figure 6			150		150		ns	
Output Settling Time					180			180		ns
Charge Injection	Q	C <sub>L</sub> = 1000pF, V <sub>GEN</sub> = 0\	$I$ , RGEN = $0\Omega$		10			10		рC
Source-Off Capacitance	Cs (off)	VS = 0V, VIN = 5V	f = 140kHz		10			10		pF
Drain-Off Capacitance	C <sub>D</sub> (off)	VS = 0V, VIN = 5V	f = 140kHz		10			10		рF
Channel-On Capacitance	CD (on) <sup>+</sup> CS (on)	$V_D = V_S = 0V$ , $V_{IN} = 0V$	f = 140kHz		30			30		рF
Off Isolation		$V_{IN} = 3V_{RMS}, Z_{L} = 1k\Omega$	f = 100kHz		72			72		dB
Crosstalk (Channel-to-Channel)		Vs = 2.0V, f = 100kHz		i	90			90		dB
SUPPLY				_						
Positive Supply Current	l+	All channels on or off		-3.0	3.8	6.5	-3.0	3.8	6.5	mA
Negative Supply Current	I-				1.0			1.0		mA
Power-Supply Range for Continuous Operation	VOP	(Note 5)		±4.5		±20	±4.5		±20	V

#### **ELECTRICAL CHARACTERISTICS**

(V+ = 15V, V- = -15V, GND = 0V,  $T_A = T_{MIN}$  to  $T_{MAX}$ , unless otherwise noted.)

		CONDITIONS		HI-201HS-2/-8			HI-201HS-5/-6/-9			
PARAMETER	SYMBOL			MIN (Note 3)	TYP (Note 4)	MAX	MIN (Note 3)	TYP (Note 4)	MAX	UNITS
SWITCH										
Analog-Signal Range	VANALOG			-15		15	-15		15	٧
Drain-Source On Resistance (Note 5)	r <sub>DS</sub> (on)	V <sub>D</sub> = ±10V,	VIN = 0.8V, IS = 1mA			75			75	Ω
Source-Off Leakage	10.4 10	V 2.0V	Vs = 14V, VD = -14V	-100		100	-50		50	nA
Current	IS (off)	VIN = 3.0V	Vs = -14V, VD = 14V	-100	_	100	-50	_	50	
Drain-Off Leakage	ID (off)	\/ 2 O\/	V <sub>D</sub> = 14V, V <sub>S</sub> = -14V	-100		100	-50		50	nA
Current		VIN = 3.0V	V <sub>D</sub> = -14V, V <sub>S</sub> = 14V	-100		100	-50		50	
Drain-On Leakge	ID (on)	V <sub>D</sub> = -14V, V <sub>IN</sub> = 0.8V V <sub>D</sub> = 14V, V <sub>IN</sub> = 0.8V		-100		100	-50		50	nA
Current (Note 6)				-100		100	-50		50	
LOGIC INPUT										
Input Current with	linh	V <sub>IN</sub> = 3.0V		-1.0		1.0	-1.0		1.0	
Input Voltage High		VIN = 15V		-1.0		1.0	-1.0		1.0	μА
Input Current with Input Voltage Low	INL	VIN = 0.8V		-1.0		1.0	-1.0		1.0	μА
DYNAMIC										
Turn-On Time	ton	See Figure 6		_	_	75	_	_	75	ns
Turn-Off Time	toff	See Figure 6				75			75	ns
SUPPLY										
Positive Supply Current	l+	All channels	s on or off			10			10	mA
Negative Supply Current	1-	All channels	s on or off	6			6			mA

Note 3: The algebraic convention where the most negative value is a minimum and the most positive a maximum is used in this data sheet.

Note 4: Typical values are for DESIGN AID ONLY, not guaranteed or subject to production testing.

Note 5: Electrical characteristics, such as on resistance, will change when power supplies other than ±15V are used.

Note 6: ID(on) is leakage from driver into on switch.

### Protecting Against \_\_\_Fault Conditions

Fault conditions occur when power supplies are turned off and input signals are still present, or when overvoltages occur at the inputs during normal operation. In either case, source-to-body diodes can be forward biased and conduct current from the signal source. If this current must be kept at low ( $\mu$ A) levels, we recommend adding external protection diodes (Figure 1).

To provide protection for overvoltages up to 20V above the supplies, place a 1N4001 or 1N914 type diode in series with the positive and negative supplies, as shown in Figure 1. Adding these diodes will reduce the analog-signal range to 1V below the positive supply and 1V above the negative supply.

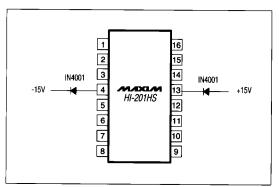


Figure 1. Protection Against Fault Conditions

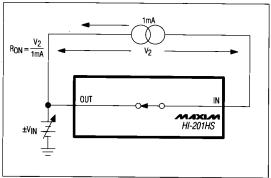


Figure 2. On Resistance

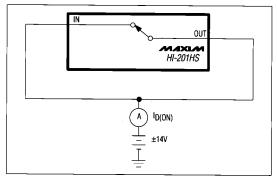


Figure 3. On Leakage Current

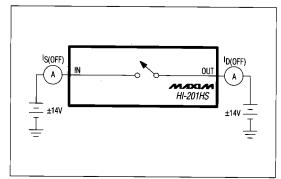


Figure 4. Off Leakage Current

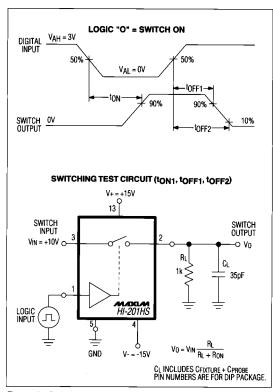
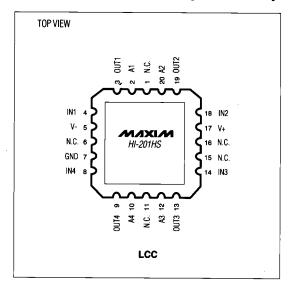
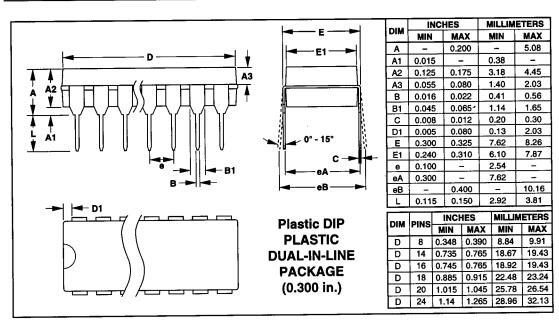


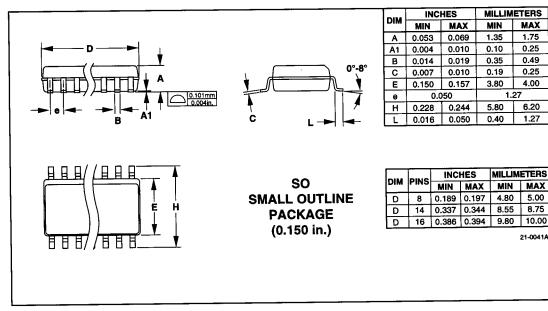
Figure 6. Switching-Time Test Circuit

#### \_ Pin Configurations (continued)

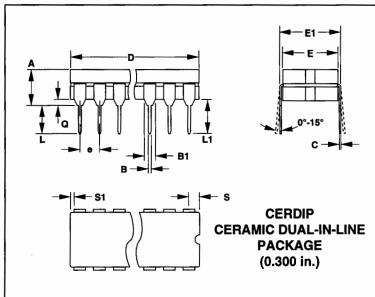


#### Package Information





#### Package Information (continued)



DIM	INC	HES	MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	_	0.200		5.08	
В	0.014	0.023	0.36	0.58	
B1	0.038	0.065	0.97	1.65	
C	0.008	0.015	0.20	0.38	
E	0.220	0.310	5.59	7.87	
E1	0.290	0.320	7.37	8.13	
е	0.1	00	2.	54	
L	0.125	0.200	3.18	5.08	
L1	0.150	_	3.81		
Q	0.015	0.070	0.38	1.78	
S	_	0.098	_	2.49	
S1	0.005	_	0.13	-	

		INC	HES	MILLIMETERS			
DIM	PINS	MIN MAX		MIN	MAX		
D	8	-	0.405	_	10.29		
D	14	-	0.785	_	19.94		
D	16	-	0.840		21.34		
D	18	_	0.960	_	24.38		
D	20	_	1.060	_	26.92		
D	24		1.280		32.51		

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